Translating Bus Exchange Switch

7WBD383

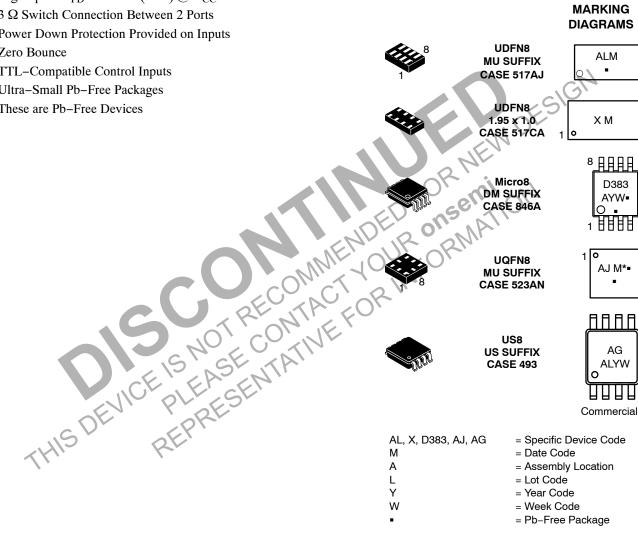
The 7WBD383 is an advanced high-speed low-power translating bus exchange switch in ultra-small footprints.

Features

- High Speed: $t_{PD} = 0.25 \text{ ns} (Max) @ V_{CC} = 4.5 \text{ V}$
- 3 Ω Switch Connection Between 2 Ports
- Power Down Protection Provided on Inputs
- Zero Bounce
- TTL-Compatible Control Inputs
- Ultra-Small Pb-Free Packages
- These are Pb-Free Devices

ON Semiconductor®

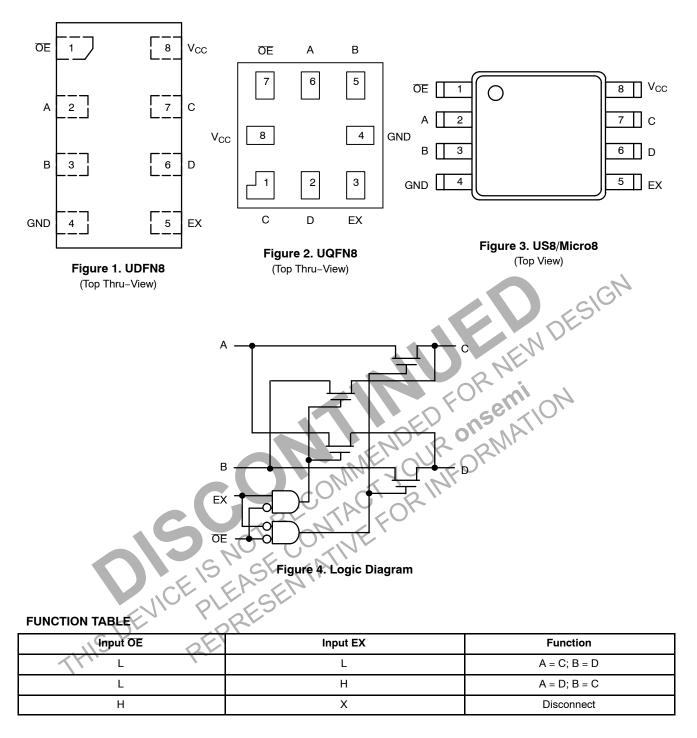
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(Note: Microdot may be in either location) *Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.



MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +7.0	V
V _{IN}	Control Pin Input Voltage	–0.5 to +7.0	V
V _{I/O}	Switch Input / Output Voltage	–0.5 to +7.0	V
۱ _{IK}	Control Pin DC Input Diode Current V _{IN} < GND	-50	mA
Ι _{ΟΚ}	Switch I/O Port DC Diode Current V _{I/O} < GND	-50	mA
Ι _Ο	ON-State Switch Current	±128	mA
	Continuous Current Through V _{CC} or GND	±150	mA
I _{CC}	DC Supply Current Per Supply Pin	±150	mA
I _{GND}	DC Ground Current per Ground Pin	±150	mA
T _{STG}	Storage Temperature Range	-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds	260	℃
TJ	Junction Temperature Under Bias	150	O` °C
θ_{JA}	Thermal Resistance US8 (Note 1) UDFN8 UQFN8 Micro8	251 111 208 392	°C/W
P _D	Power Dissipation in Still Air at 85°C US8 UDFN8 UQFN8 Micro8	498 1127 601 319	mW
MSL	Moisture Sensitivity	Level 1	
F _R	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage Human Body Mode (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 N/A	V
ILATCHUP	Latchup Performance Above V _{CC} and Below GND at 125 °C (Note 5)	±200	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality Should not be assumed, damage may occur and reliability may be affected.
Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.
Tested to EIA / JESD22-A114-A.
Tested to JESD22-C101-A.
Tested to JESD22-C101-A.

- 5. Tested to EIA / JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Max	Unit
V _{CC}	Positive DC Supply Voltage	4.0	5.5	V	
V _{IN}	Control Pin Input Voltage		0	5.5	V
V _{I/O}	Switch Input / Output Voltage	0	5.5	V	
T _A	Operating Free-Air Temperature		-55	+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate	Control Input Switch I/O	0 0	5 DC	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

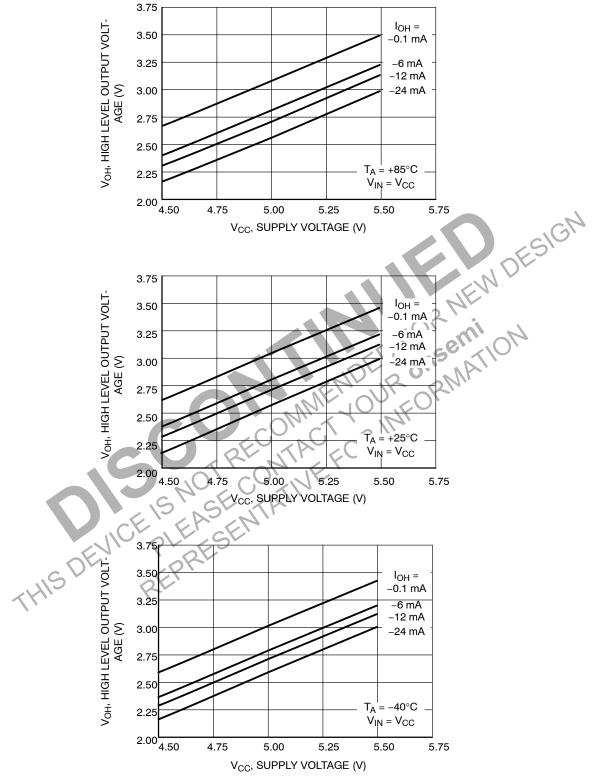
		Vcc		T _A = 25°C		T _A = −55°C to +125°C			
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Unit
VIK	Clamp Diode Voltage	I _{I/O} = -18 mA	4.5			-1.2		-1.2	V
V _{IH}	High-Level Input Voltage (Control)		4.0 to 5.5	2.0			2.0		V
V _{IL}	Low-Level Input Voltage (Control)		4.0 to 5.5			0.8		0.8	V
V _{OH}	Output Voltage High	See Figure 5							
I _{IN}	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	5.5			±0.1		±1.0	μΑ
I _{OFF}	Power Off Leakage Current	V _{I/O} = 0 to 5.5 V	0			±0.1		±1.0	μΑ
I _{CC}	Quiescent Supply Current	$I_{O} = 0,$ $\frac{V_{IN} = V_{CC} \text{ or } 0 \text{ V}}{\overline{OE} = \text{GND}}$ $\overline{OE} = V_{CC}$	5.5			±1.0 ±0.1		±1.0 ±1.0	mA μA
ΔI_{CC}	Increase in Supply Current (Control Pin)	One input at 3.4 V; Other inputs at V_{CC} or GND	5.5				NDE	2.5	mA
R _{ON}	Switch ON Resistance	$V_{I/O} = 0,$ $I_{I/O} = 64 \text{ mA}$ $I_{I/O} = 30 \text{ mA}$	4.5		3 3			7 7	Ω
		$V_{I/O} = 2.4,$ $I_{I/O} = 15 \text{ mA}.$			15	50	1017	50	
		V _{I/O} = 2.4, I _{I/O} = 15 mA	4.0		50	70	•	70	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

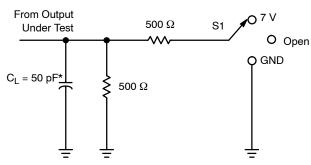
			V _{cc}	T _A = 25 °C		T _A = −55°C to +125°C			
Symbol	Parameter S	Test Condition	(V)	Min	Тур	Max	Min	Max	Unit
t _{PD}	Propagation Delay, Bus to Bus	See Figure 6	4.0 to 5.5			0.25		0.25	ns
t _{PD-EX}	Propagation Delay, EX to Bus	See Figure 6 and Figure 7	4.0 to 5.5			4.5		4.5	ns
t _{EN}	Output Enable Time	See Figure 6	4.5 to 5.5	0.8	2.5	4.2	0.8	4.2	ns
			4.0	0.8	3.0	4.6	0.8	4.6	
t _{DIS}	Output Disable Time		4.5 to 5.5	0.8	3.0	4.8	0.8	4.8	ns
			4.0	0.8	2.9	4.4	0.8	4.4	
C _{IN}	Control Input Capacitance	$V_{IN} = 5 \text{ or } 0 \text{ V}$	5.0		2.5				pF
C _{IO(ON)}	Switch On Capacitance	Switch ON	5.0		10				pF
C _{IO(OFF)}	Switch Off Capacitance	Switch OFF	5.0		5				pF

TYPICAL DC CHARACTERISTICS



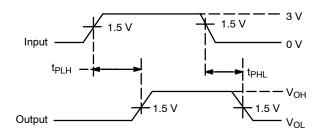


AC LOADING AND WAVEFORMS

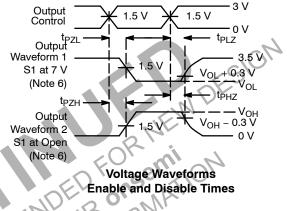


Test	S1
t _{PD}	Open
t _{PLZ} /t _{PZL}	7 V
t _{PHZ} /t _{PZH}	Open

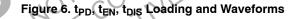
*CL includes probes and jig capacitance.



Voltage Waveforms Propagation Delay Times



- 6. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control
 7. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
- 8. The outputs are measured one at a time, with one transition per measurement.
- 9. t_{PLZ} and t_{PHZ} are the same as t_{DIS} .
- 10. t_{PZL} and t_{PZH} are the same as t_{EN} .
- 11. t_{PHL} and t_{PLH} are the same as t_{PD}



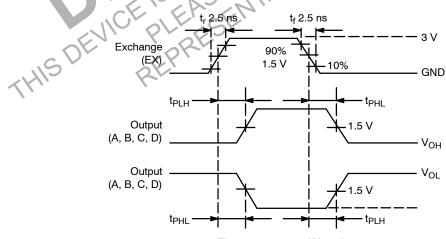


Figure 7. t_{PD-EX} Waveforms

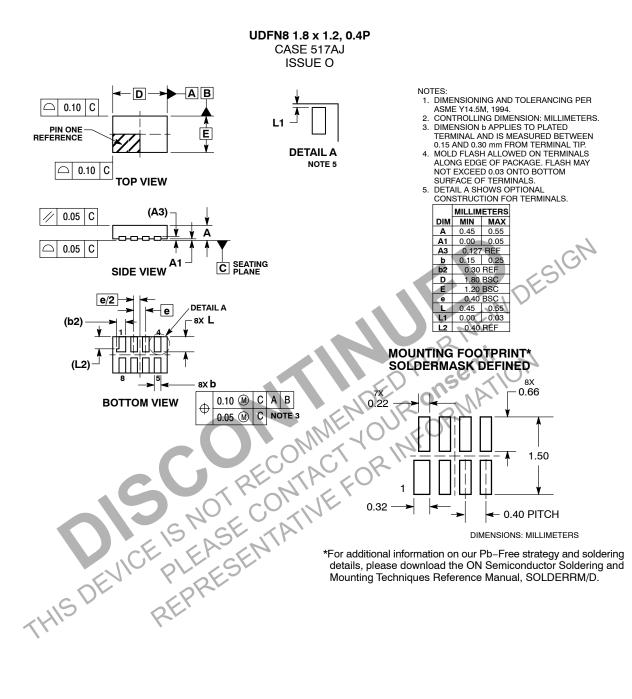
ORDERING INFORMATION

Device	Package	Shipping [†]
7WBD383USG	US8 (Pb-Free)	3000 / Tape & Reel
7WBD383MUTAG	UDFN8 (Pb-Free)	3000 / Tape & Reel
7WBD383AMUTCG	UQFN8 (Pb-Free)	3000 / Tape & Reel
7WBD383DMR2G	Micro8 (Pb-Free)	4000 / Tape & Reel
7WBD383DMUTCG	UDFN8, 1.95 x 1.0, 0.5 mm Pitch (Pb–Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

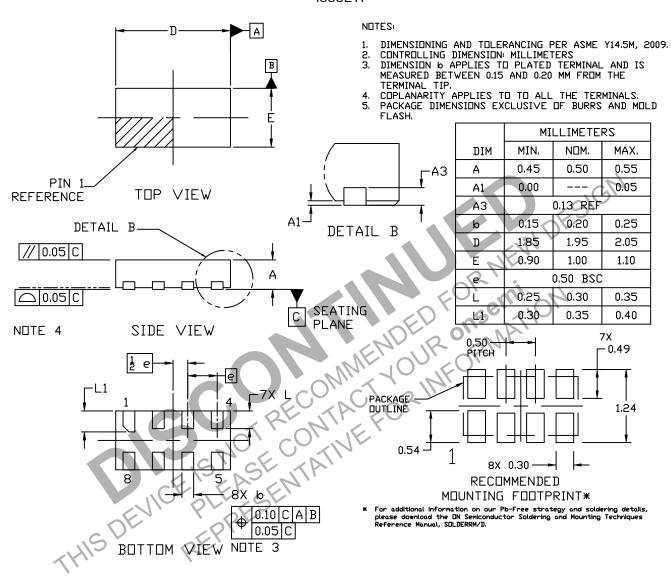
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PACKAGE DIMENSIONS

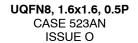


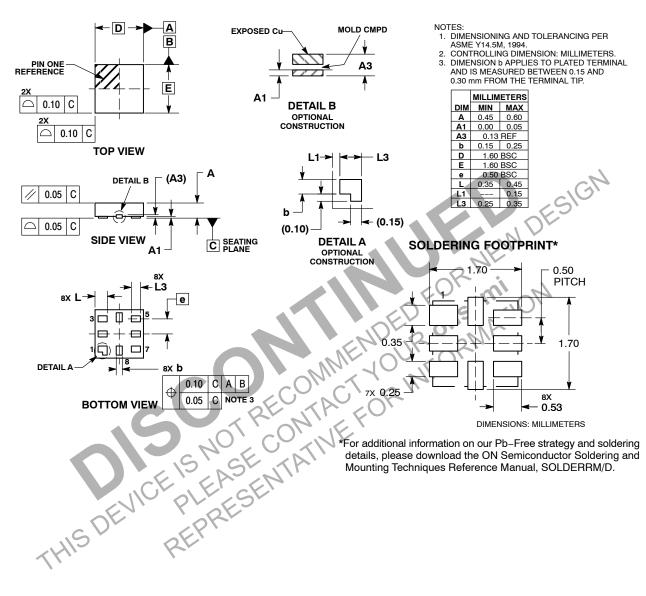
PACKAGE DIMENSIONS

UDFN8 1.95x1.0, 0.5P CASE 517CA ISSUE A

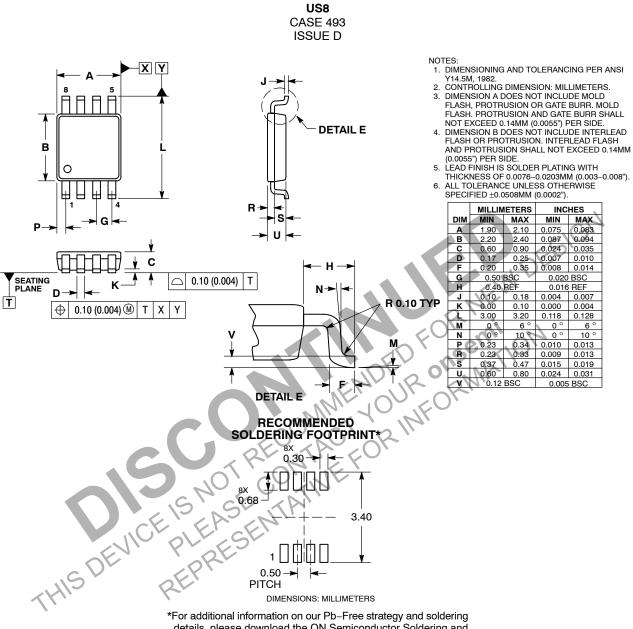


PACKAGE DIMENSIONS





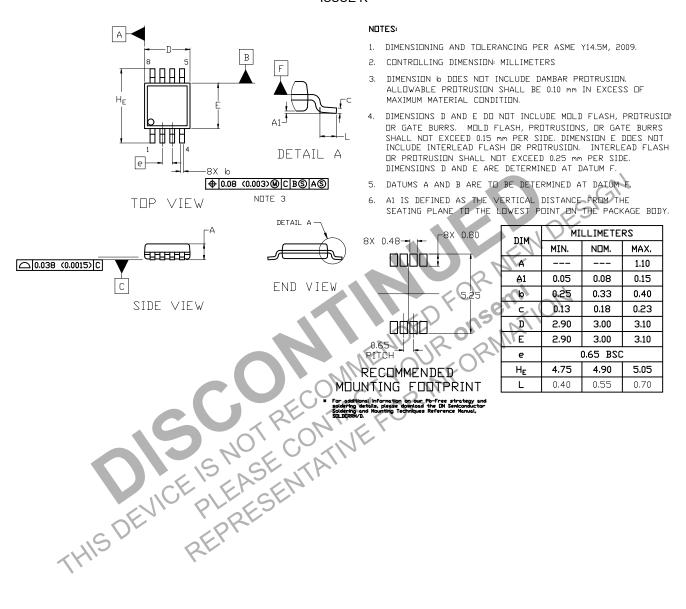
PACKAGE DIMENSIONS



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

Micro8 CASE 846A ISSUE K



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